

## ESDALC6V1M3

## Dual low capacitance TRANSIL™ array for ESD protection

## Main product applications

Where transient overvoltage protection in ESD sensitive equipment is required, such as:

- Computers
- Printers
- Communication systems
- Cellular phone handsets and accessories
- Video equipment

#### **Features**

- 2 unidirectional low capacitance TRANSIL diodes
- Breakdown Voltage V<sub>BR</sub> = 6.1 V min
- Low diode capacitance (11 pF typ at 0 V)
- Low leakage current < 0.5 µA</p>
- Very small PCB area: 0.6 mm²
- RoHS compliant

### **Description**

The ESDALC6V1M3 is a monolithic array designed to protect 1 line or 2 lines against ESD transients.

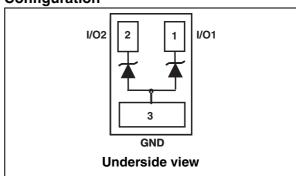
The device is ideal for applications where both reduced line capacitance and board space saving are required.

#### **Benefits**

- High ESD protection level
- High integration
- Suitable for high density boards



#### Configuration



#### Order code

Part number	Marking
ESDALC6V1M3	К

#### Complies with the following standards

IEC61000-4-2 level 4:

15 kV (air discharge) 8 kV (contact discharge)

MIL STD 883E-Method 3015-7: class 3

HBM (Human Body Model)

TRANSIL is a trademark of STMicroelectronics

## 1 Characteristics

Table 1. Absolute ratings ( $T_{AMB} = 25^{\circ} \text{ C} - \text{limiting values}$ )

Symbol		Parameter		Value	Unit
V <sub>PP</sub>	ESD discharge	IEC61000-4-2 air discharge IEC61000-4-2 contact discharge		± 15 ± 8	kV
P <sub>PP</sub>	Peak pulse powe	Peak pulse power dissipation (8/20 $\mu$ s) <sup>(1)</sup> $T_j$ initial = $T_{AMB}$			W
I <sub>pp</sub>	Repetitive peak pulse current (8/20 µs)			3	Α
Tj	Junction temperature			125	° C
Tstg	Storage temperature range			-55 + 150	° C
T <sub>L</sub>	Maximum lead temperature for soldering during 10 s			260	° C
T <sub>OP</sub>	Operating temperature range			-40 + 125	° C

<sup>1.</sup> For a surge greater than the maximum values, the diode will fail in short-circuit.

Table 2. Electrical characteristics  $(T_{AMB} = 25^{\circ} C)$ 

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Symbol	Parameter	1
V <sub>RM</sub>	Stand-off voltage	ı <sub>F</sub>
V <sub>BR</sub>	Breakdown voltage	
V <sub>CL</sub>	Clamping voltage	V <sub>CL</sub> V <sub>BR</sub> V <sub>RM</sub>
I <sub>RM</sub>	Leakage current @ V <sub>RM</sub>	IRM
I <sub>PP</sub>	Peak pulse current	I R
αΤ	Voltage temperature coefficient	Slope= 1/R <sub>d</sub>
V <sub>F</sub>	Forward voltage drop	

Parameter	Test condition	Min	Тур	Max	Unit
V <sub>BR</sub>	I <sub>R</sub> = 1 mA	6.1		7.2	V
I <sub>RM</sub>	V <sub>RM</sub> = 5 V			0.5	μΑ
R <sub>d</sub>			1.1		Ω
αΤ	I <sub>R</sub> = 1 mA			4.2	10 <sup>-4</sup> /°C
С	$V_R = 0 \text{ V, } F = 1 \text{ MHz, } V_{OSC} = 30 \text{ mV}$		11		pF

0.00

-10.00

-20.00

-30.00

-40.00 100.0k

Figure 1. S21 attenuation measurement results of each channel

1.0G

Figure 2. Analog crosstalk measurements between channels

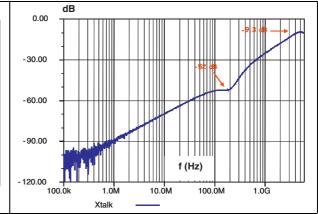


Figure 3. ESD response to IEC61000-4-2 (+15 kV air discharge) on each channel

10.0M

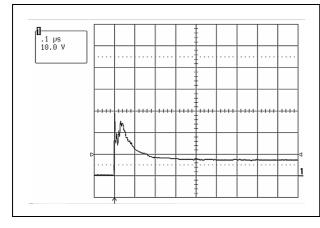
1.0M

Att 1

f (Hz)

100.0M

Figure 4. ESD response to IEC61000-4-2 (-15 kV air discharge) on each channel.



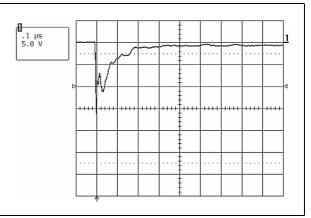
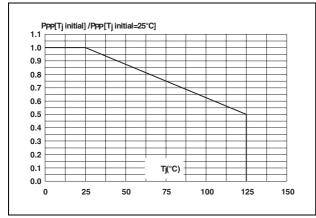


Figure 5. Relative variation of peak pulse power versus initial junction temperature

Figure 6. Peak pulse power versus exponential pulse duration



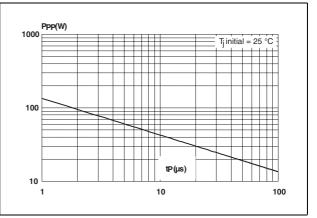
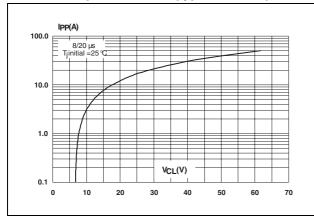


Figure 7. Clamping voltage versus peak pulse current (typical values)

Figure 8. Forward voltage drop versus peak forward current (typical values)



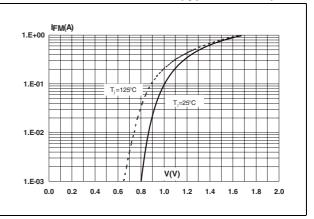
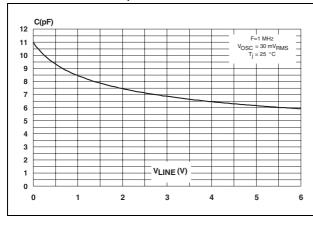
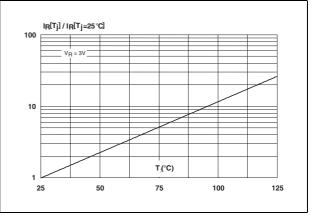


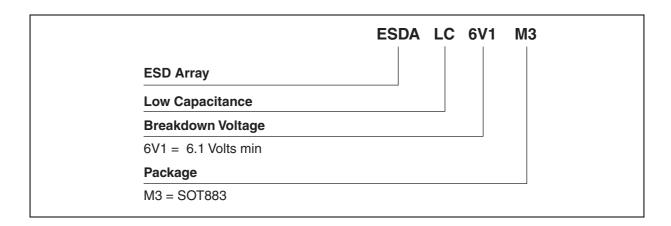
Figure 9. Junction capacitance versus reverse voltage applied (typical values)

Figure 10. Relative variation of leakage current versus junction temperature (typical values)



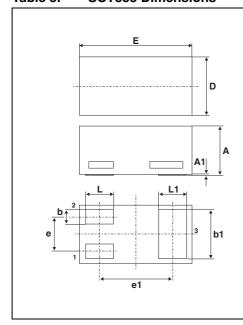


## 2 Ordering information scheme



# 3 Package information

Table 3. SOT883 Dimensions



	Dimensions					
Ref.	Millimetres		Inches			
	Min	Тур	Max	Min	Тур	Max
Α	0.45		0.52	0.18		0.2
A1	0.00		0.05	0.00		0.02
b	0.10	0.15	0.20	0.04	0.06	0.08
b1	0.45	0.50	0.55	0.18	0.20	0.22
D		0.60			0.24	
Е		1.00			0.39	
е		0.35			0.14	
e1		0.65			0.26	
L	0.20	0.25	0.30	0.08	0.10	0.12
L1	0.20	0.25	0.30	0.08	0.10	0.12

Figure 11. Footprint

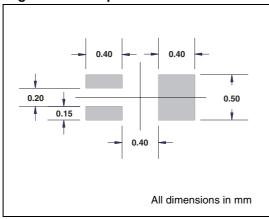
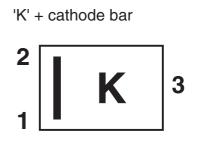


Figure 12. Marking



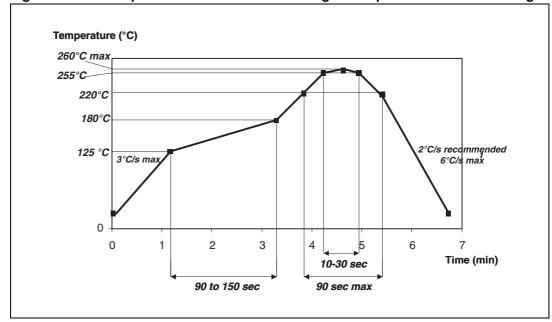
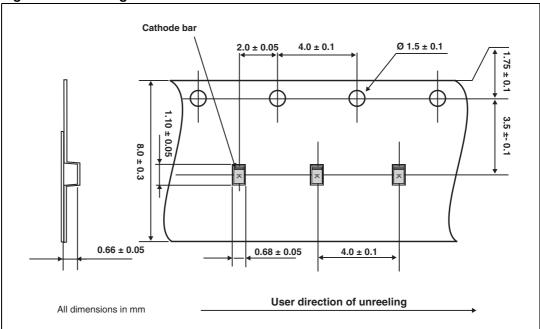


Figure 13. ST Ecopack® recommended soldering reflow profile for PCB mounting





In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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# 4 Ordering information

Part number	Marking	Package	Weight	Bulk qty	Delivery mode
ESDALC6V1M3	K	SOT883	0.96 mg	30 000	Tape and reel

## 5 Revision history

Date	Revision	Changes
04-Aug-2005	1	Initial release.
23-May-2006 2		Reformated to current standards. Added soldering reflow profile diagram.
16-Jun-2006	3	Updated tape and reel illustration (Figure 14).

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